National Semiconductor

PRELIMINARY

74LCX373
Low-Voltage Octal Transparent Latch with 5V Tolerant Inputs and Outputs

General Description

The LCX373 consists of eight latches with TRI-STATE® outputs for bus organized system applications. The device is designed for low voltage (3.3V) V_{CC} applications with capability of interfacing to a 5V signal environment.

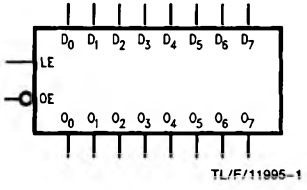
The LCX373 is fabricated with an advanced CMOS technology to achieve high speed operation while maintaining CMOS low power dissipation.

Features

- 5V tolerant inputs and outputs
- Ideal for low power/low noise 2.7V to 3.6V applications
- Power-down static overvoltage protection on inputs and outputs
- Outputs source/sink 24 mA
- Guaranteed simultaneous switching noise level
- Available in SOIC JEDEC, SOIC EIAJ and TSSOP
- Implements patented Quiet Series noise/EMI reduction circuitry
- Functionally compatible with the 74 series 373
- Latchup performance exceeds 300 mA
- ESD performance:
  Human Body Model > 2000V
  Machine Model > 250V

Ordering Code: See Section 11

Logic Symbols



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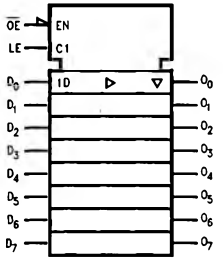
IEEE/IEC



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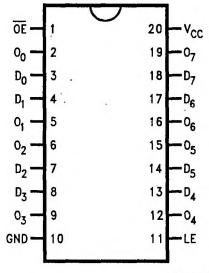
Connection Diagram

Pin Assignment for SOIC and TSSOP



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Pin Names	Description
D_0–D_7	Data Inputs
LE	Latch Enable Input
$\overline{OE}$	Output Enable Input
O_0–O_7	TRI-STATE Latch Outputs

	SOIC JEDEC	SOIC EIAJ	TSSOP JEDEC
Order Number	74LCX373WM 74LCX373WMX	74LCX373SJ 74LCX373SJX	74LCX373MTCX
See NS Package Number	M20B	M20D	MTC20

Preliminary Data: National Semiconductor reserves the right to make changes at any time without notice.

Functional Description

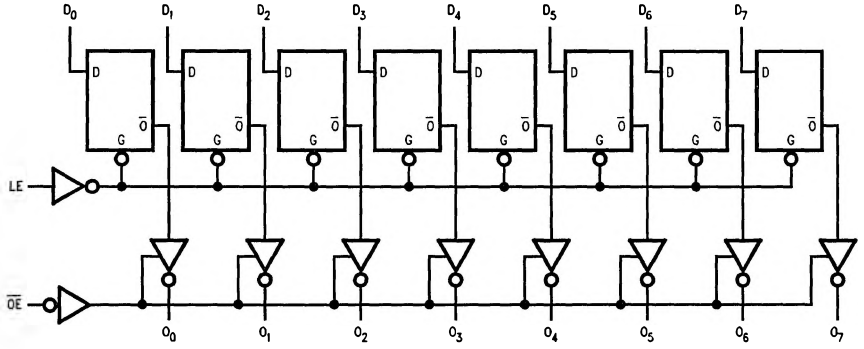
The LCX373 contains eight D-type latches with TRI-STATE standard outputs. When the Latch Enable (LE) input is HIGH, data on the D_n inputs enters the latches. In this condition the latches are transparent, i.e. a latch output will change state each time its D input changes. When LE is LOW, the latches store the information that was present on the D inputs a setup time preceding the HIGH-to-LOW transition of LE. The TRI-STATE standard outputs are controlled by the Output Enable ($\overline{OE}$) input. When $\overline{OE}$ is LOW, the standard outputs are in the 2-state mode. When $\overline{OE}$ is HIGH, the standard outputs are in the high impedance mode but this does not interfere with entering new data into the latches.

Truth Table

Inputs			Outputs
LE	$\overline{OE}$	D_n	O_n
X	H	X	Z
H	L	L	L
H	L	H	H
L	L	X	O_0

H = HIGH Voltage Level
L = LOW Voltage Level
Z = High Impedance
X = Immaterial
O_0 = Previous O_0 before HIGH to LOW transition of Latch Enable

Logic Diagram



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Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings (Note 1)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/Distributors for availability and specifications.

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Voltage (V_I)	−0.5V to +7.0V
Output Voltage (V_O)	
Outputs TRI-STATE	−0.5V to +7.0V
Outputs Active (Note 2)	−0.5V to V_{CC} + 0.5V
DC Input Diode Current (I_{IK}) V_I < 0	−50 mA
DC Output Diode Current (I_{OK})	
V_O < 0	−50 mA
V_O > V_{CC}	+50 mA
DC Output Source/Sink Current (I_{OH}/I_{OL})	±50 mA
DC V_{CC} or Ground Current per Supply Pin (I_{CC} or I_{GND})	±100 mA
Storage Temperature Range (T_{STG})	−65°C to +150°C

Note 1: *The "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the "Electrical Characteristics" table are not guaranteed at the absolute maximum ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.*

Note 2: *I_O Absolute Maximum Rating must be observed.*

Recommended Operating Conditions

Supply Voltage	
Operating	2.0V to 3.6V
Data Retention Only	1.5V to 3.6V
Input Voltage (V_I)	0V to 5.5V
Output Voltage (V_O)	
Output in Active State	0V to V_{CC}
Output in "OFF" State	0V to 5.5V
Output Current I_{OH}/I_{OL}	
V_{CC} = 3.0V to 3.6V	±24 mA
V_{CC} = 2.7V to 3.0V	±12 mA
Free Air Operating Temperature (T_A)	−40°C to +85°C
Minimum Input Edge Ratge ($\Delta t/\Delta V$)	
V_{IN} = 0.8V to 2.0V, V_{CC} = 3.0V	10 ns/V

DC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	T_A = −40°C to +85°C		Units	Conditions
			Min	Max		
V_{IH}	High Level Input Voltage	2.7–3.6	2.0		V	V_{OUT} ≤ 0.1V or ≥ V_{CC} − 0.1V
V_{IL}	Low Level Input Voltage	2.7–3.6		0.8		
V_{OH}	High Level Output Voltage	2.7–3.6	V_{CC} − 0.2		V	I_{OH} = −100 μA
		2.7	2.2			I_{OH} = −12 mA
		3.0	2.4			I_{OH} = −18 mA
		3.0	2.2			I_{OH} = −24 mA
V_{OL}	Low Level Output Voltage	2.7–3.6		0.2	V	I_{OL} = 100 μA
		2.7		0.4		I_{OL} = 12 mA
		3.0		0.55		I_{OL} = 24 mA
I_I	Input Leakage Current	2.7–3.6		±5.0	μA	0 ≤ V_I ≤ 5.5V
I_{OZ}	TRI-STATE Output Leakage	2.7–3.6		±5.0	μA	0 ≤ V_O ≤ 5.5V V_I = V_{IH} or V_{IL}
I_{OFF}	Power Off Leakage Current	0		100	μA	V_I or V_O = 5.5V
I_{CC}	Quiescent Supply Current	2.7–3.6		10	μA	V_I = V_{CC} or GND
				±10	μA	3.6 ≤ (V_I, V_O) ≤ 5.5V
ΔI_{CC}	Increase in I_{CC} per Input	2.7–3.6		500	μA	V_{IH} = V_{CC} − 0.6V

AC Electrical Characteristics: See Section 2 for Test Methodology

Symbol	Parameter	V_{CC} (V)	$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF		Units
			Min	Max (Note 2)	
t_{PHL} t_{PLH}	Propagation Delay D_n to O_n	2.7 3.0–3.6	1.5 1.5	9.0 8.0	ns
t_{PHL} t_{PLH}	Propagation Delay LE to O_n	2.7 3.0–3.6	1.5 1.5	9.5 8.5	ns
t_{PZH} t_{PZL}	Output Enable Time	2.7 3.0–3.6	1.5 1.5	9.5 8.5	ns
t_{PHZ} t_{PLZ}	Output Disable Time	2.7 3.0–3.6	1.5 1.5	8.5 7.5	ns
t_S	Setup Time D_n to LE	2.7 3.0–3.6	2.5 2.5		
t_H	Hold Time D_n to LE	2.7 3.0–3.6	1.5 1.5		ns
t_W	LE Pulse Width	2.7 3.0–3.6	4.0 4.0		ns
t_{OSHL}, t_{OSLH}	Output to Output Skew (Note 1)	3.0		1.0	ns

Note 1: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH to LOW (t_{OSHL}) or LOW to HIGH (t_{OSLH}). Parameter guaranteed by design.

Note 2: The maximum AC limits are design targets. Actual performance will be specified upon completion of characterization.

Dynamic Switching Characteristics: See Section 2 for Test Methodology

Symbol	Parameter	V_{CC} (V)	$T_A = 25°C$ Typical	Units	Conditions
V_{OLP}	Quiet Output Dynamic Peak V_{OL}	3.3	0.8	V	$C_L = 50$ pF, $V_{IH} = 3.3$V, $V_{IL} = 0$V
V_{OLV}	Quiet Output Dynamic Valley V_{OL}	3.3	0.8	V	$C_L = 50$ pF, $V_{IH} = 3.3$V, $V_{IL} = 0$V

Capacitance

Symbol	Parameter	Typical	Units	Conditions
C_{IN}	Input Capacitance	7	pF	V_{CC} = Open $V_I = 0$V or V_{CC}
C_{OUT}	Output Capacitance	12	pF	$V_{CC} = 3.3$V $V_I = 0$V or V_{CC}
C_{PD}	Power Dissipation Capacitance	32	pF	$V_{CC} = 3.3$V $V_I = 0$V or V_{CC} F = 10 MHz

Note 1: Guaranteed by design.